



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Declaration for Patent Application

[] Supplemental (37 C.F.R. §1.67)

As a named inventor, I hereby declare that:

My residence, mailing address and citizenship are as stated next to my name;

I believe I am the original, first and sole inventor (if only one name is listed) or an original, first and joint inventor (if plural names are listed in the signatory page(s) commencing at page 2 hereof) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Multi-Gate Heterostructured Field Effect Transistor

the specification of which (check one)

[] is attached hereto.

[X] was filed on December 5, 2003 as United States Application Number 10/729,426.

[] was filed on [PCT Filing Date] as PCT International Application No. [PCT Appl'n No.] [OPTION and assigned United States Application No. []].

[] and was amended on [] (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. §1.56, including for continuation-in-part applications, material information which became available between the filing date of the prior application and the national or PCT international filing date of the continuation-in-part application.

I hereby claim foreign priority benefits under 35 U.S.C. 119 or 365 of any foreign application(s) for patent or inventor's certificate, or of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or of any PCT international application having a filing date before that of the application on which priority is claimed:

<u>Prior Foreign Application(s)</u>			Priority Not Claimed	Certified Copy Filed?	
				YES	NO
_____ (Number)	_____ (Country)	_____ (Day/Month/Year filed)	[]	[]	[]
_____ (Number)	_____ (Country)	_____ (Day/Month/Year filed)	[]	[]	[]
_____ (Number)	_____ (Country)	_____ (Day/Month/Year filed)	[]	[]	[]

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole

or first inventor Samson Mil'shtein

Samson Mil'shtein

Inventor's Signature

Date

03/26/04

Residence 6 Warwick Drive

Chelmsford, Massachusetts 01824

Citizenship U.S.A.

Mailing Address Same as above

Full name of second joint

inventor, if any Peter Ersland

Inventor's Signature

Date

Residence 1B Trot Road

Littleton, Massachusetts 01460

Citizenship U.S.A.

Mailing Address Same as above

Full name of third joint

inventor, if any Shivarajiv Kumar Somisetty

Inventor's Signature

Date

Residence ~~163 University Ave #3~~ 76 Gershom Avenue, Apt. #3

Lowell, Massachusetts 01854

Citizenship India

Mailing Address Same as above

Full name of fourth joint

inventor, if any Carlos Gil

Inventor's Signature

Date

Residence 16 Bear Hill Road

Billerica, Massachusetts 01821

Citizenship U.S.A.

Mailing Address Same as above



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				YES	NO
<u>(Number)</u>	<u>(Country)</u>	<u>(Day/Month/Year filed)</u>	[]	[]	[]
<u>(Number)</u>	<u>(Country)</u>	<u>(Day/Month/Year filed)</u>	[]	[]	[]
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Full name of sole

or first inventor Samson Mil'shtein

Inventor's Signature _____ Date _____

Residence 6 Warwick Drive
Chelmsford, Massachusetts 01824

Citizenship U.S.A.

Mailing Address Same as above

Full name of second joint

inventor, if any Peter Ersland

Inventor's Signature Peter Ersland Date 19 May 2004

Residence 1B Trot Road
Littleton, Massachusetts 01460

Citizenship U.S.A.

Mailing Address Same as above

Full name of third joint

inventor, if any Shivarajiv Kumar Somisetty

Inventor's Signature _____ Date _____

Residence 163 University Ave #3
Lowell, Massachusetts 01854

Citizenship India

Mailing Address Same as above

Full name of fourth joint

inventor, if any Carlos Gil

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Mailing Address Same as above

